Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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H7N0307LD, H7N0307LS, H7N0307LM

Silicon N Channel MOS FET High Speed Power Switching

REJ03G1121-0700

(Previous: ADE-208-1516E)

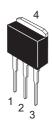
Rev.7.00 Apr 07, 2006

Features

- Low on-resistance $R_{DS (on)} = 4.6 \text{ m}\Omega \text{ typ.}$
- Low drive current
- 4.5 V gate drive device can be driven from 5 V source

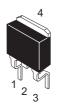
Outline

RENESAS Package code: PRSS0004AE-A (Package name: LDPAK (L))



H7N0307LD

RENESAS Package code: PRSS0004AE-C (Package name: LDPAK (S)-(2))



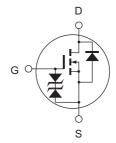
H7N0307LM

RENESAS Package code: PRSS0004AE-B (Package name: LDPAK (S)-(1))



- 1. Gate
- 2. Drain
- 3. Source
- 4. Drain





Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

| Item | Symbol | Value | Unit |
|---|-------------------------------|-------------|------|
| Drain to source voltage | V _{DSS} | 30 | V |
| Gate to source voltage | V _{GSS} | ±20 | V |
| Drain current | I _D | 60 | Α |
| Drain peak current | I _{D (pulse)} Note 1 | 240 | Α |
| Body to drain diode reverse drain current | I _{DR} | 60 | Α |
| Channel dissipation | Pch Note 2 | 90 | W |
| Channel to case thermal impedance | θ ch-c | 1.39 | °C/W |
| Channel to ambient thermal impedance | θ ch-a | 89 | °C/W |
| Channel temperature | Tch | 150 | °C |
| Storage temperature | Tstg | -55 to +150 | °C |

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

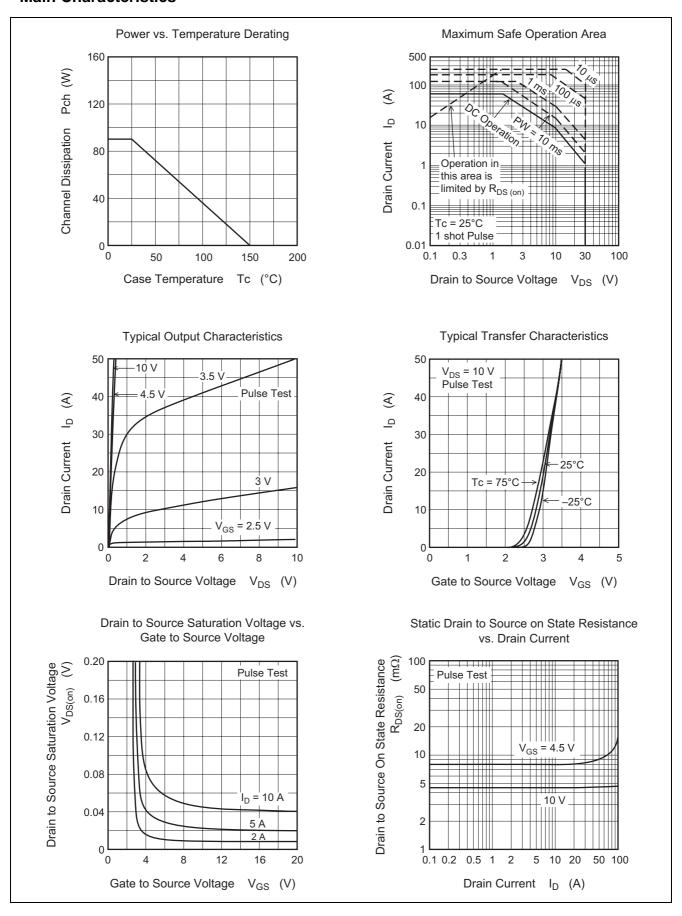
Electrical Characteristics

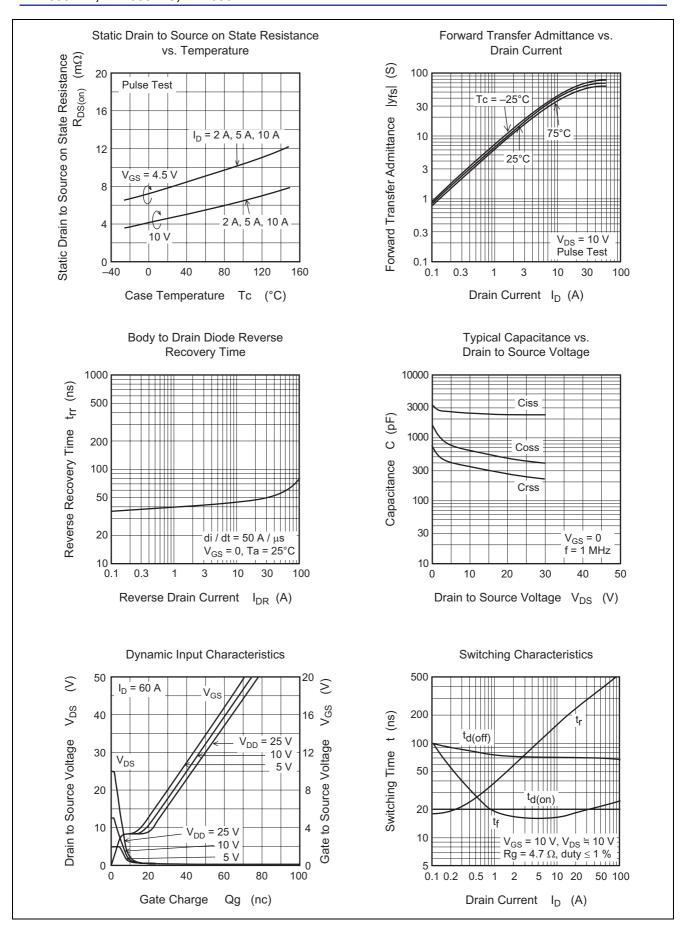
 $(Ta = 25^{\circ}C)$

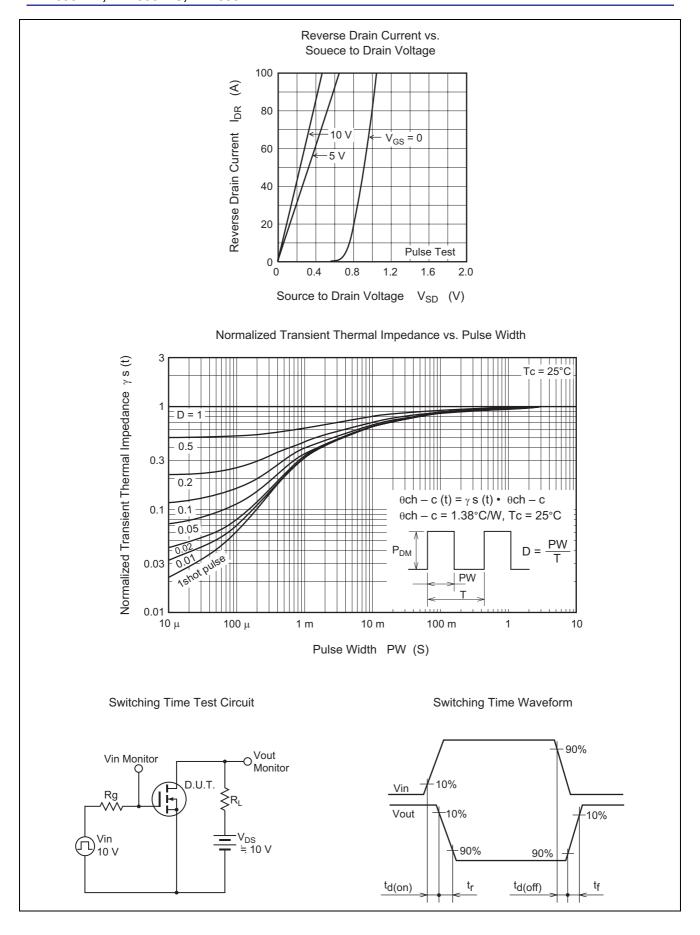
| Item | Symbol | Min | Тур | Max | Unit | Test Conditions |
|--------------------------------------|-----------------------|-----|------|------|------|--|
| Drain to source breakdown voltage | V _{(BR) DSS} | 30 | _ | | > | $I_D = 10 \text{ mA}, V_{GS} = 0$ |
| Gate to source breakdown voltage | V _(BR) GSS | ±20 | _ | | V | $I_G = \pm 100 \ \mu A, \ V_{DS} = 0$ |
| Gate to source leak current | I _{GSS} | _ | _ | ±10 | μΑ | $V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$ |
| Zero gate voltage drain current | I _{DSS} | _ | _ | 10 | μΑ | $V_{DS} = 30 \text{ V}, V_{GS} = 0$ |
| Gate to source cutoff voltage | $V_{GS\ (off)}$ | 1.0 | _ | 2.5 | V | $I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}^{\text{Note 3}}$ |
| Static drain to source on state | R _{DS (on)} | _ | 4.6 | 5.8 | mΩ | $I_D = 30 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note 3}}$ |
| resistance | | _ | 8.0 | 11.5 | mΩ | $I_D = 30 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note 3}}$ |
| Forward transfer admittance | y _{fs} | 40 | 65 | _ | S | $I_D = 30 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note 3}}$ |
| Input capacitance | Ciss | _ | 2500 | _ | pF | V _{DS} = 10 V |
| Output capacitance | Coss | _ | 650 | _ | pF | $V_{GS} = 0$ |
| Reverse transfer capacitance | Crss | _ | 350 | _ | pF | f = 1 MHz |
| Total gate charge | Qg | _ | 40 | _ | nC | V _{DD} = 10 V |
| Gate to source charge | Qgs | _ | 7 | _ | nC | V _{GS} = 10 V |
| Gate to drain charge | Qgd | _ | 8 | _ | nC | $I_D = 60 \text{ A}$ |
| Turn-on delay time | t _{d (on)} | _ | 20 | _ | ns | $V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}$ |
| Rise time | t _r | _ | 300 | _ | ns | $R_L = 0.33 \Omega$ |
| Turn-off delay time | t _{d (off)} | _ | 70 | _ | ns | $Rg = 4.7 \Omega$ |
| Fall time | t _f | _ | 20 | _ | ns | |
| Body to drain diode forward voltage | V_{DF} | _ | 0.92 | _ | V | I _F = 60 A, V _{GS} = 0 |
| Body to drain diode reverse recovery | t _{rr} | _ | 60 | _ | ns | I _F = 60 A, V _{GS} = 0 |
| time | | | | | | di _F /dt = 50 A/μs |

Note: 3. Pulse test

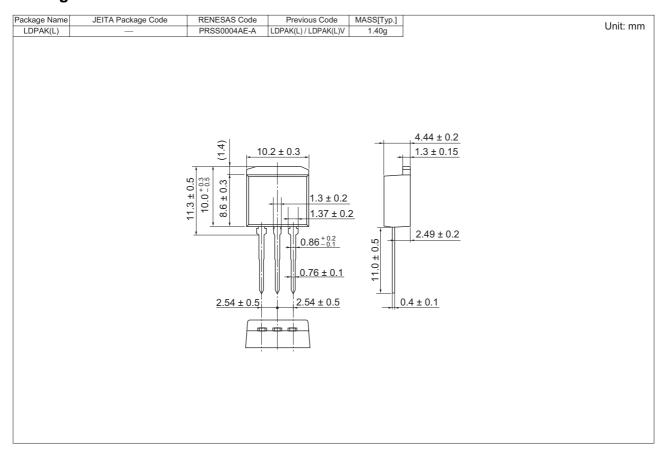
Main Characteristics

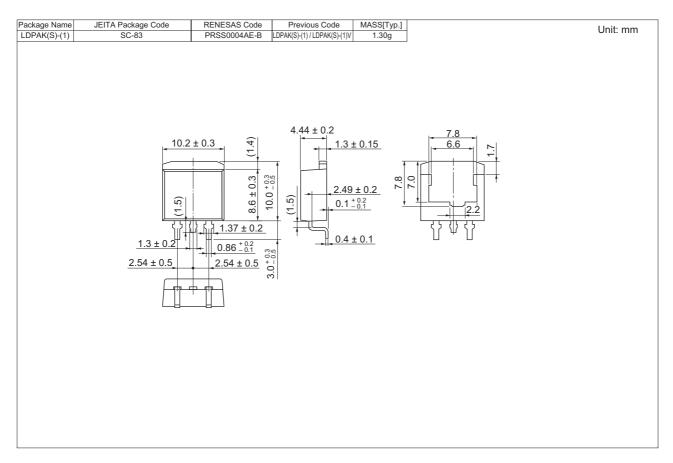


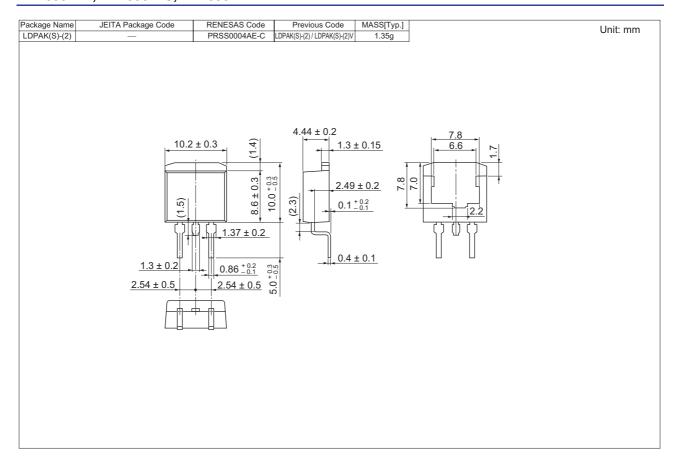




Package Dimensions







Ordering Information

| Part Name | Quantity | Shipping Container |
|---------------|----------|-----------------------|
| H7N0307LD-E | 500 pcs | Box (Conductive Sack) |
| H7N0307LSTL-E | 1000 pcs | Taping |
| H7N0307LMTL-E | 1000 pcs | Taping |

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